

# **DTA113T**

## PNP SILICON TRANSISTOR

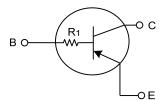
# PNP DIGITAL TRANSISTOR (BUILT- IN BIAS RESISTORS)

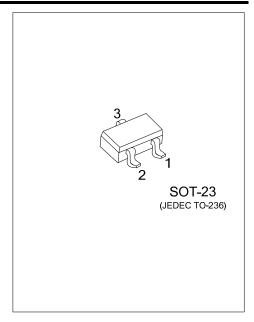
### FEATURES

\* Built-in bias resistors that implies easy ON/OFF applications.

\* The bias resistors are thin-film resistors with complete isolation to allow positive input.

#### EQUIVALENT CIRCUIT





#### ORDERING INFORMATION

Ordering Number	Deekage	Pin Assignment			Deaking		
Ordering Number	Package	1	2	3	Packing		
DTA113TG-AE3-R	SOT-23	Е	В	С	Tape Reel		
Note: Pin assignment: E: Emitter B: Base C: Collector							
DTA113TG-AE3-R	(1) R: Tape Reel						
(2)Package Type (2) AE3: SOT-23							
(3)Green Package	(3) G: Halogen Free and Lead Free						

#### ■ MARKING



#### ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-50	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Collector Current	Ι <sub>C</sub>	-100	mA
Peak Collector Current	I <sub>CM</sub>	-200	mA
Collector Power Dissipation	Pc	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified)

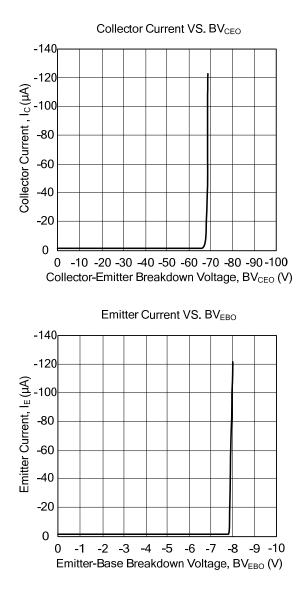
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =-100μΑ, R <sub>BE</sub> =∞	-50			V
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =-10mA, I <sub>B</sub> =-0.5mA			-0.3	V
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> =-50V, I <sub>E</sub> =0			-0.1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1mA	100			
Input Resistance	R <sub>IN</sub>		0.7	1.0	1.3	kΩ
Current Gain Bandwidth Product	f⊤	V <sub>CE</sub> =-6V, I <sub>E</sub> =10mA		150		MHz

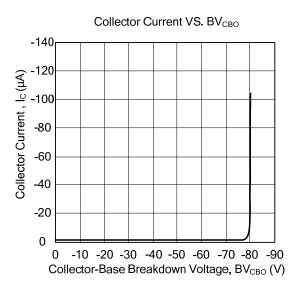


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#### TYPICAL CHARACTERISTICS





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